

# Supporting Information

*Ruiqi Zhao*<sup>1</sup>, *Jianing Zhuang*<sup>2</sup>, *Zilin Liang*<sup>2,3</sup>, *Tianying Yan*<sup>3\*</sup>, and *Feng Ding*<sup>2\*</sup>

<sup>1</sup>School of Physics and Chemistry, Henan Polytechnic University, Henan 454003, China

<sup>2</sup>Institute of Textiles and Clothing, Hong Kong Polytechnic University, Kowloon, Hong Kong, China

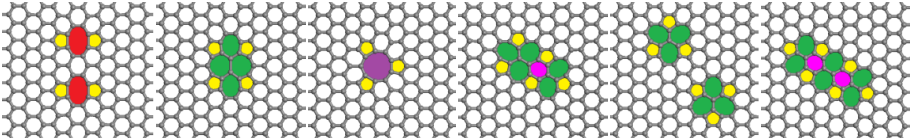
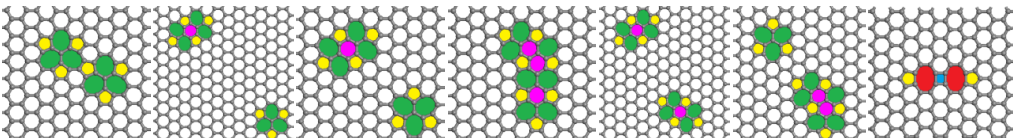
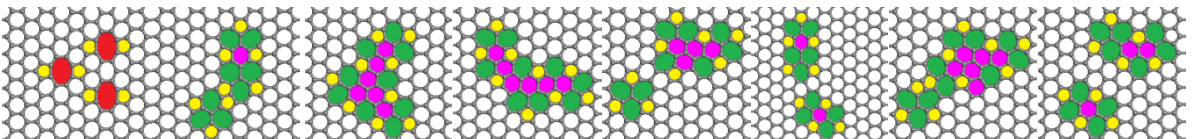
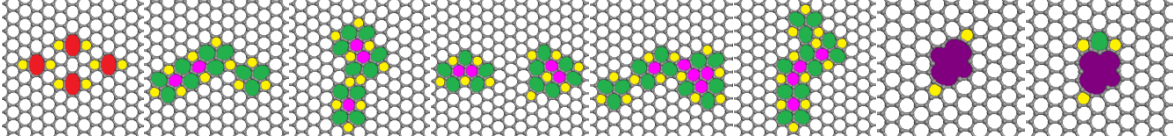
<sup>3</sup>Institute of New Energy Material Chemistry, Synergetic Innovation Center of Chemical Science and Engineering (Tianjin), Tianjin Key Laboratory of Metal and Molecule Based Material Chemistry, Nankai University, Tianjin 300071, China

\*Authors to whom correspondence should be addressed: [tyan@nankai.edu.cn](mailto:tyan@nankai.edu.cn), [feng.ding@polyu.edu.hk](mailto:feng.ding@polyu.edu.hk).

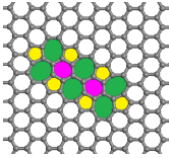
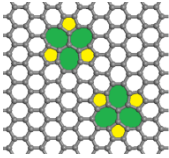
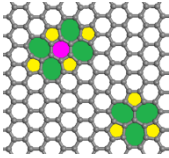
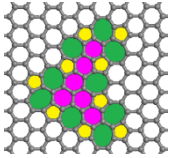
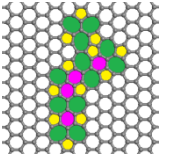
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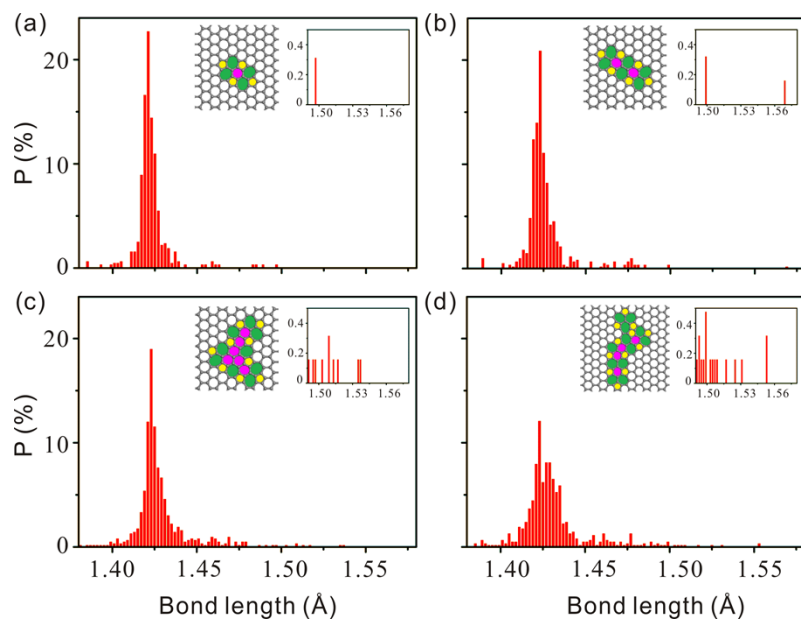
**Table S1**  $E_{fs}$  (eV) of certain configurations observed in the NEMD simulation of  $V_n$ s, for  $n = 4, 6,$  and  $8$ . The optimizations were performed with both REBO2 potential and DFT (in parentheses). The 5-, rotated 6-, 7-, and 8- membered rings and hole-structures are emphasized with yellow, purple, green, red, and dark purple colors, respectively. The haeckelites are distinguished by merged (M-) or separated (S-) with the total number of 5|7 pairs (see the main text).

$V_n$ s	Representative configurations and $E_{fs}$
$V_4$	 2-585    M-4-57    5559    M-5-57    S-6-57    M-6-57
	16.51(16.15)    13.01(11.77)    10.80(10.28)    11.70(10.64)    13.22(12.27)    11.36(9.96)
$V_4$	 S-6-57    S-7-57    S-7-57    M-7-57    S-8-57    S-8-57    58-4-85
	12.89(12.09)    13.98(12.59)    14.09(12.72)    13.28(10.65)    14.45(12.50)    15.25(13.43)    12.66(11.36)
$V_6$	 3-585    S-8-57    M-9-57    M-9-57    S-9-57    S-9-57    S-10-57    S-10-57
	22.74(21.86)    17.40(15.60)    16.85(14.49)    18.79(16.17)    19.16(17.10)    19.69(17.69)    20.18(17.81)    20.79(18.22)
$V_8$	 4-585    S-10-57    S-10-57    S-11-57    S-12-57    S-12-57    hole    hole
	29.23 (27.65)    22.86 (20.77)    23.71(21.24)    25.64 (23.26)    24.63(21.74)    17.18(18.27)    17.52(18.28)    17.51(18.31)

**Table S2** The area of pentagon and heptagon of the 57 pair of certain haeckelites, and the resulted area compensation by 57 pair relative to two hexagons in the perfect graphene.

MVs	$V_4$			$V_6$	$V_8$
Configurations					
Average area of pentagons ( $\text{\AA}^2$ )	3.59	3.61	3.62	3.56	3.66
Average area of heptagons ( $\text{\AA}^2$ )	7.76	7.87	7.75	7.67	7.72
$S_5 + S_7 = n S_6$	2.15	2.18	2.16	2.13	2.16
Compensation(%)	45	54	56	39	48

Note: In the perfect graphene, C-C length is 1.424  $\text{\AA}$ , and the area of a hexagon is 5.27  $\text{\AA}^2$ .



**Fig. S1** Probability distributions of bond lengths in representative configurations of  $V_nS$ :  $V_2$  (a),  $V_4$  (b),  $V_6$  (c), and  $V_8$  (d). The configurations and partial enlarged regions with bond length exceeds  $1.49 \text{ \AA}$  are also shown as insets.